TSXdB.00

High Frequency Broadband Attenuators Electrical and Thermal Test Report

Juan Ayala, Mo Hasanovic March 15, 2021 Revision 2 (July 14th, 2021)



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Scope

The purpose of this test report is to present the electrical and thermal performance of SMT high frequency broadband attenuators covering frequencies from DC to 40 GHz (product family TSXdB.00) developed under the project DD-233610. The report will show test data collected during the tests performed on these products. Both the pre-test simulation analysis as well as the tests on real prototypes will be displayed and analyzed. For a successful evaluation of the products at high frequencies, it is of a paramount importance for the products to be mounted on the test fixture using clearly defined mounting instructions. This report contains these mounting instructions for a future reference to be used by both the internal and external users. In addition, the test procedure is included with the test equipment used and best testing practices implemented.

Thermal performance has also been presented through a simulation and a real-life test. Thermal finite element analysis (FEA) simulations are carried out to calculate the maximum power handling of the family of parts in different environments (with different mounting constituents). The power test has been conducted in a destruct fixture that was described in the report. Finally, the set of samples has been exposed to a rigorous qualification that included Group A, Group B and Group C tests as per test plan TP-9293.

The test samples passed all the qualification test requirements. The test results that will be presented in this test report are an evidence of a successful test and viability of the products to be released into customers' applications.

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Specifications

The products have been designed for a broad frequency band from DC to 40 GHz. The performance is also evaluated up to 50 GHz. The product offering spans attenuation values from 0 dB to 10 dB in increments of 1 dB as well as high attenuation values of 15 dB and 20 dB. The size of the product is identical for all values, $0.060"\times0.040"\times0.010"$. These products were made using a thin film based processes on an Alumina ceramic substrate. Detailed specifications for these two products are shown in Tables and Figures below.

TSXD	B.00			
ITEM	PARAMETER	REQUIREMENT	LIMITS	UNITS
1	Nominal Impedance	$50 \pm 10\%$	-	Ω
2	Frequency Range	DC - 40	-	GHz
3	VSWR (DC–20 GHz)	1.30:1	maximum	-
4	VSWR (20–40 GHz)	1.40:1	maximum	-
5	Attenuation	0 – 10 dB, 15 dB, 20 dB	minimum	dB
4	Attenuation Accuracy (DC-20 GHz)	± 0.50	minimum	dB
5	Attenuation Accuracy (20–40 GHz)	±0.75	minimum	dB
8	Temperature Coefficient	± 200	maximum	ppm/°C
9	Input Power	0.5	minimum	Watts
10	Operating Temperature	-55 to +150	-	°C
11	Non-Operating Temperature	-65 to +150	-	°C

Table 1. Electrical and Non-Electrical Requirements for TSXDB.00

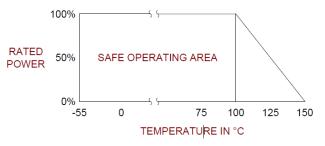


Figure 1. Power Derating at Temperature

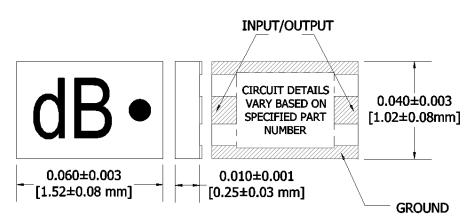


Figure 2. 2D Drawings for TSXDB.00 - Mechanical Footprint

Theory

RF attenuator, marketed by Smiths Interconnect under various product names represents an RF passive component broadly used in the industry for many applications including mobile networks, high power amplifiers, military applications, instrumentation, and many more. Broadband frequency attenuator series TSX presented in this report is applicable in wide frequency range, from DC to 40 GHz, providing attenuation of 0 to 10 dB in increments of 1 dB plus high attenuation values of 15 dB and 20 dB. The product is also characterized by its high reliability, compactness, and low-cost. For most of the values, this product is realized as a simple pi-network as shown in Figure 3. Higher attenuation values are design as a series connection of two pi-networks that produce lower attenuation value.

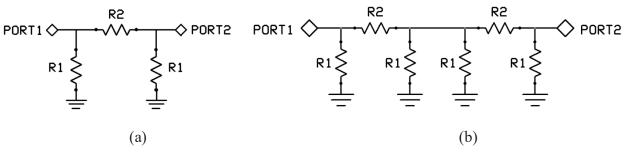


Figure 3. Attenuator circuit model options: (a) Pi-configuration (0 - 10 dB), (b) Double Pi-configuration (15 dB and 20 dB values)

All different models of the broadband high frequency attenuators have been modeled, simulated and tuned through iterative design process using 3D electromagnetic tools. Figure 4 shows the baseline model of TSX attenuator design in Ansys HFSS, both as a stand-alone part as well as mounted and interfacing the test fixture.

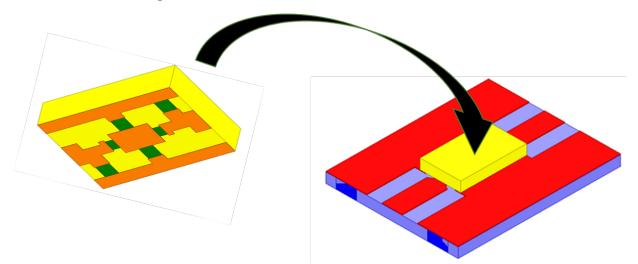


Figure 4. Electrical Model of TSX broadband high frequency attenuator, as a standalone and as mounted on the test board

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After the designs have been optimized for a nominal performance, the tolerance analysis has been conducted that considered substrate thickness and dielectric constant variations, transmission line dimensional tolerances, and variations in the bulk resistivity and shape of the resistors (Figure 5).

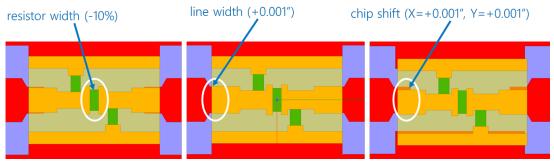


Figure 5. Positional tolerance of the chips on the application board (modeling in 3D electromagnetic software)

No out-of-spec performance has been observed during the tolerance analysis as shown on Figure 6 for three typical values of 1 dB, 6 dB, and 20 dB.

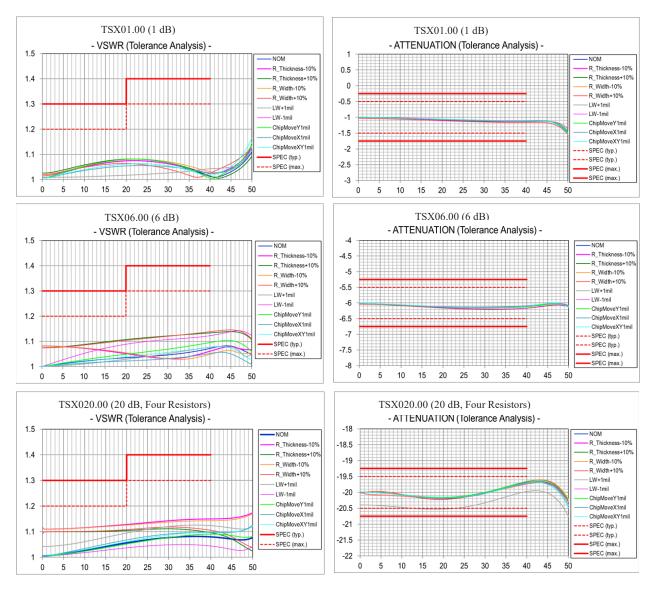


Figure 6. Electrical performance of three typical TSX attenuator values - 1 dB, 6 dB, and 20 dB

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Test Fixture Choice

The test fixture that was chosen to test this product was standardized to cover all the broadband attenuator values of TSX series. The fixture consists of a test board made with Rogers 4350 (0.0133" thickness) and two Southwest field replaceable female end launch 1.85mm connectors (1892-04A-6), see Figure 7.

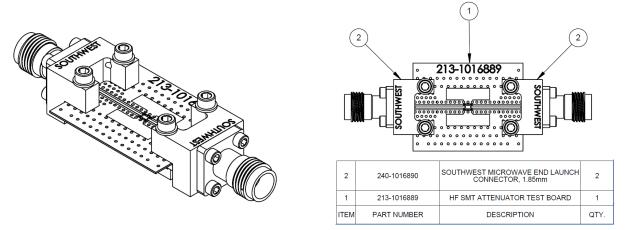


Figure 7. Test Fixture used to test Developed Prototypes.

The 1.85 mm jack (female) end launch connector used for the tests at frequencies DC - 50 GHz is shown in Figure 8. It is important to mention that the selection of the connector pin (see dimensions ϕA) on the connector (1.85 mm or 2.4 mm) affects the connector launch performance and thus must be chosen as directed.

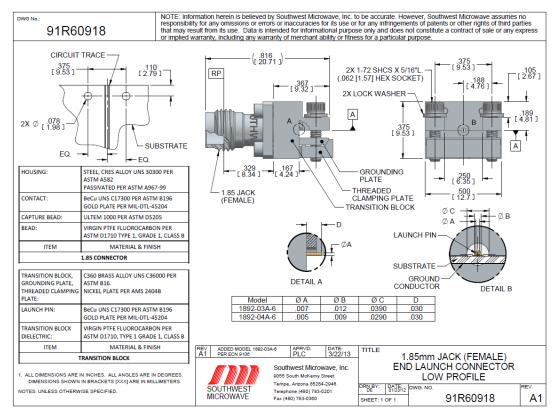


Figure 8. Southwest Microwave 1.85 mm connector used in tests at frequencies DC-42.5 GHz (drawing)

Mounting Instructions

First step in properly mounting the Thermopad for testing is to carefully inspect all the components of the test fixture to be assembled. Special attention should be given to the test board edges (Figure 18a). Common PCB manufacturing often leave rough edges that can cause fixture assembly issues. The edges of the test board can usually be cleaned up using fine grit sandpaper. (Figure 9b).

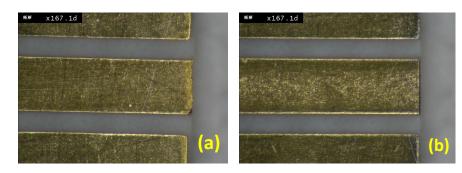


Figure 9. Test board transmission line: (*a*) rough edge (before cleaning), (*b*) smooth edge (after cleaning)

The TSX chip attenuator should also be inspected to ensure the edges are cleanly cut and have no jagged edges prior to being installed on the test board. To avoid any potential electrical failures, the TSX chip attenuator needs to be properly positioned (centered) and soldered in place. Introduction of the solder mask around the footprint area where the chip attenuator is to be soldered helps this positional alignment. The TSX chip attenuator is soldered onto the test board using Sn96 solder. Care should be taken to insure there is no solder run-out into the area where the DUT is to be mounted.

The final step in the fixture assembly is to mount the connector to the test board. Things to look for at this step is to center the connector pin on the transmission line and to ensure the connector is flush with the edge of the test board to avoid undesired air gaps (Figure 10). Use of a microscope is essential to ensuring that the connector is mounted properly.

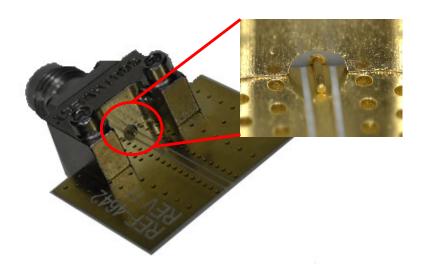


Figure 10. Connector pin alignment on the test board

Figure 11 shows details of the DUT mounting positions for the test board used to test TSX chip attenuators.

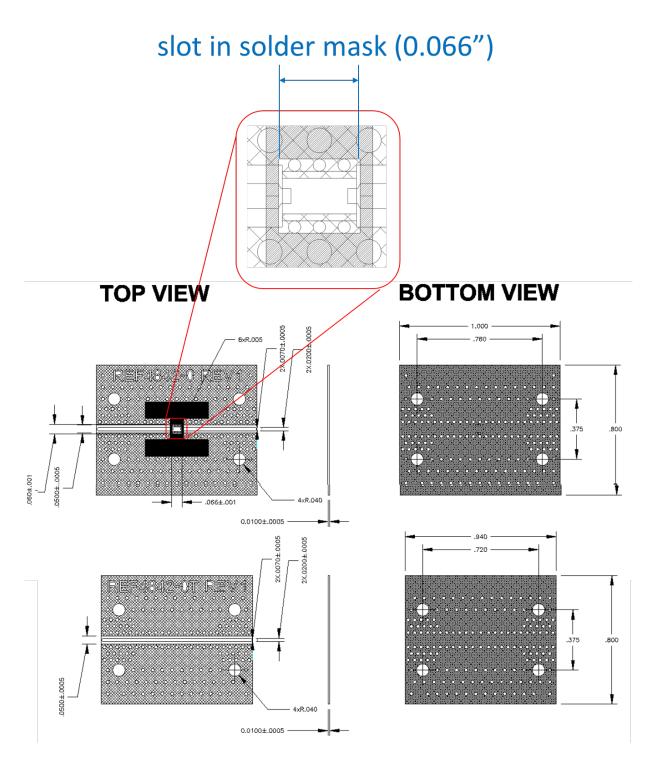


Figure 11. Detailed view of the test board used to test broadband attenuators of TSX series

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The mounting instructions are shown on the block diagram (Figure 12). The fully assembled test fixture (Figure 13) consists of the test board with the DUT installed using proper mounting practices described above. The Southwest microwave connector is seen on each side of the fixture.

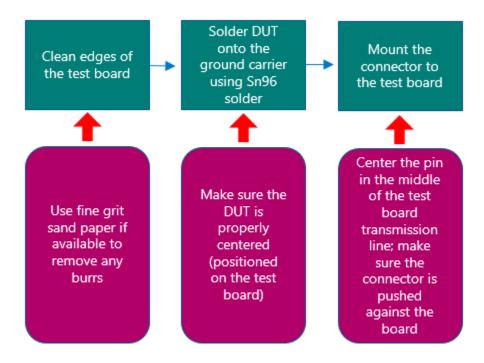


Figure 12. The Mounting instructions – Flow Chart

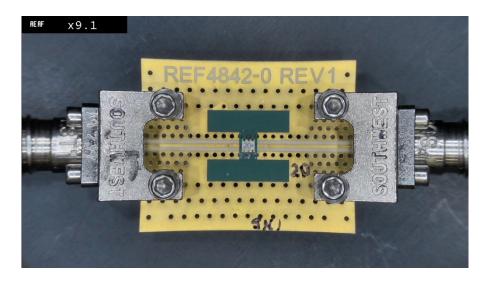
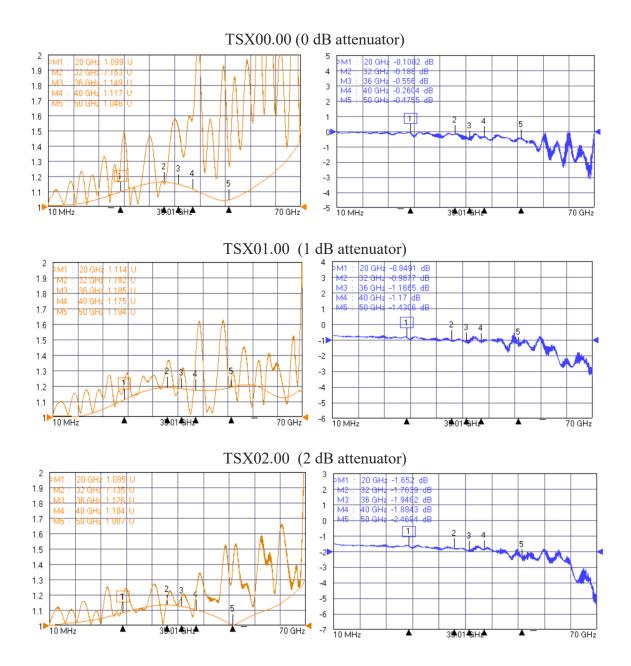


Figure 13. Fully assembled test fixture for the test of broadband high frequency attenuators of TSX series

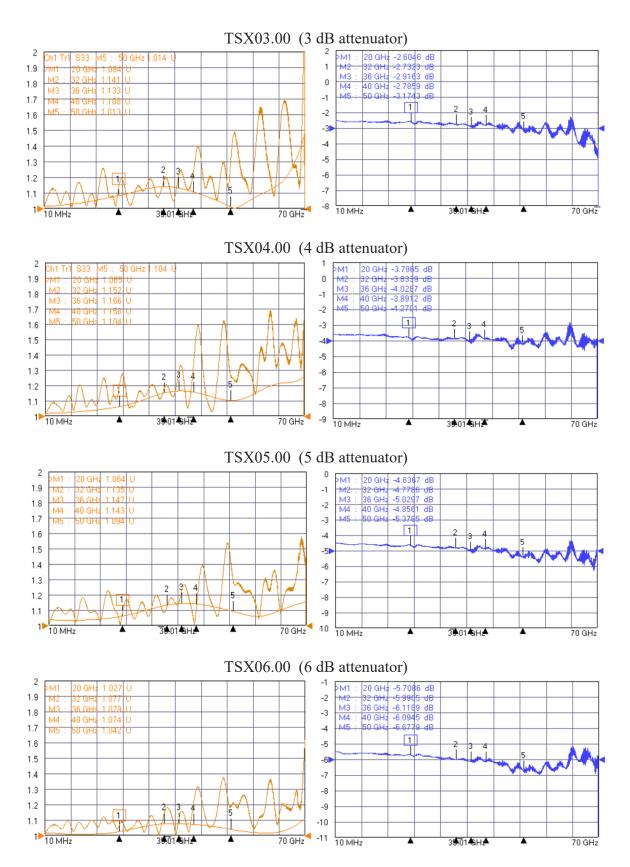
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RF Test Results

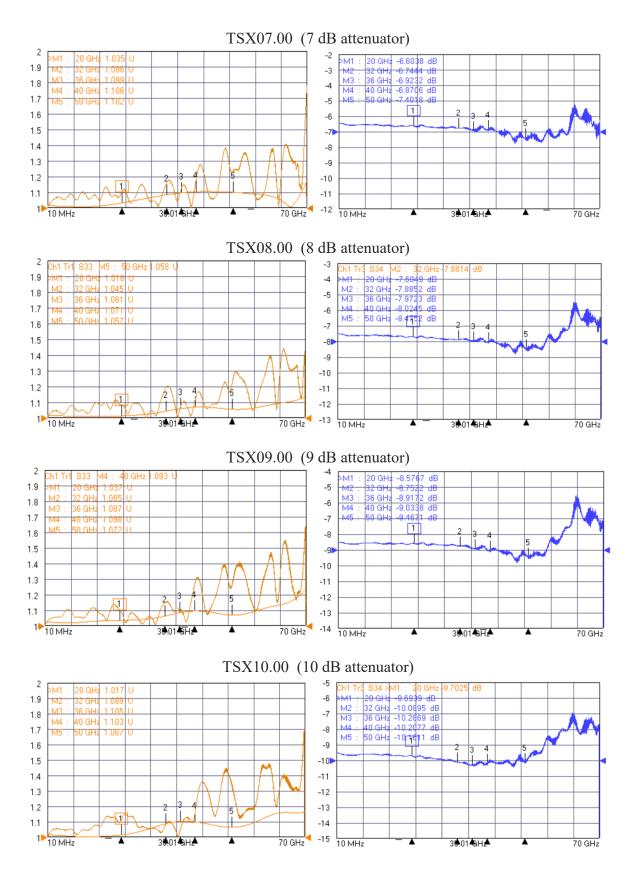
Typical performance of the full product portfolio of TSXdB.00 chip attenuators is shown in Figure 14. Both VSWR (ungated) and attenuation (with the fixture loss removed) is shown. The prototypes exhibit a very repetitive VSWR performance under 1.50:1 and attenuation within ± 1 dB for the entire frequency band 17 – 22 GHz.



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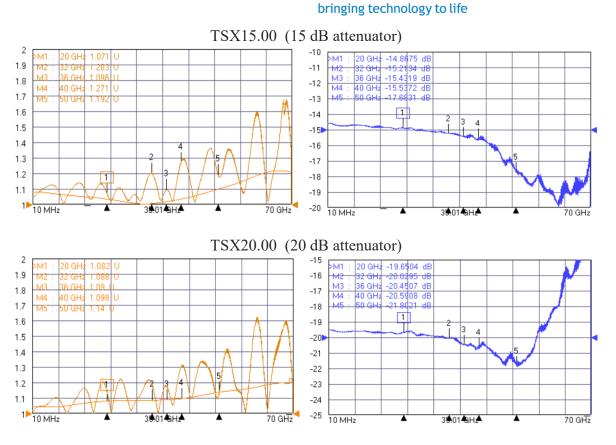


Figure 14. Typical RF performance of TSXdB.00 series: gated and ungated VSWR (left), attenuation (right)

Power Test

One device from the group (20dB) was RF tested to verify its pre-burn-in performance on an Anritsu MS4647B VNA (TE91819), see Figure 15.

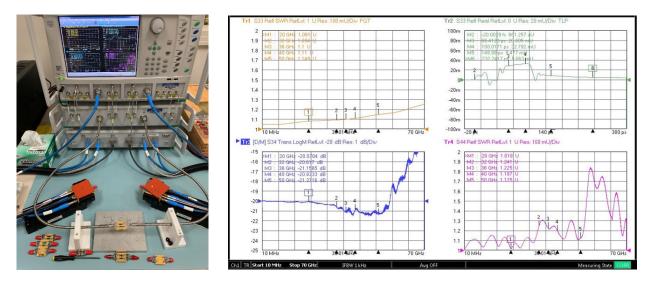


Figure 15. Pre-burn RF test of a typical 20 dB broadband attenuator: test setup (left), tested RF performance (right)

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The device was then DC resistance tested using an Extech EX505 DMM (TE92005) to calculate DCA. The device was then mounted onto an aluminum block with Nitrous oxide thermal compound and placed on an Aluminum heatsink. Input DC Power and the output load (32-1036 at 49.8 Ω) were connected via cables, with the input being cut to connect to the power supply leads (Figure 16).

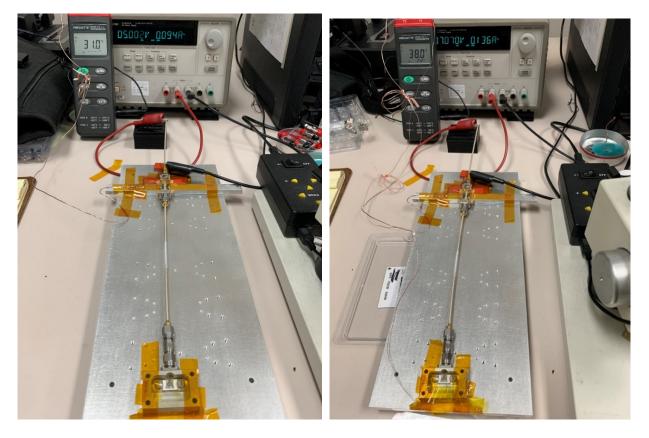


Figure 16. 20dB chip attenuator burn-in setup shown at half-power at .5Watts (right) and at fullpower of 1 Watt (left)

A K-type thermocouple was placed on the top surface of the device (hottest external spot) This temperature was recoded using an Omega HH303 thermometer (TE 30080) along with the input voltage and current from the HP E3634A Precision Power Supply (TE10965). The device underwent 15hrs at .5W with a 38-minute power ramp and experienced absolutely no change in DC Resistance after 2Hrs stabilization period. The device then underwent 405hrs at 1.0W with a 3.5hr power ramp and experienced a -.43% change in DC Attenuation after a >2Hrs stabilization period (Figure 17).

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DUT # 4			- : 1		
DUT #1		Initial DCR	Final	% Δ DCR	Δ DCR ppm
RAB	Series	82.50	82.30	-0.24	-2424
RAC	Parallel	51.60	51.50	-0.19	-1938
RBC	Parallel	51.60	51.70	0.19	1938
	Zə	50	50		
	Zin	50.55	50.43		
	Zout	50.55	50.62		
	DCA (dB)	19.89	19.80		
	% Δ DCA	-0.43	%		

DATE / TIME	E.T. (Hrs.)	VOLTS	AMPS	OHMS	WATTS	TOP TEMP	Comments
7/9/20 5:52 PM	0:00:00	2.24	0.039	57.44	0.09	24.2	
7/9/20 5:54 PM	0:02:00	3.16	0.058	54.48	0.18	25.5	
7/9/20 5:56 PM	0:04:00	3.87	0.072	53.75	0.28	27.3	
7/9/20 5:58 PM	0:06:00	4.47	0.084	53.21	0.38	29.1	
7/9/20 6:00 PM	0:08:00	5	0.094	53.19	0.47	31	
7/9/20 6:30 PM	0:38:00	5	0.094	53.19	0.47	31.9	
							Stop test. Measure DCA after
7/10/20 9:15 AM	15:23:00	5	0.094	53.19	0.47	31.9	2Hr cool down. No Change
7/10/20 11:20 AM	0:00:00	5	0.094	53.19	0.47	28.3	Restart test. Ramp up to 1W.
7/10/20 11:25 AM	0:05:00	5.47	0.104	52.60	0.57	30.8	
7/10/20 11:35 AM	0:15:00	5.47	0.104	52.60	0.57	32.8	
7/10/20 12:10 PM	0:50:00	5.47	0.104	52.60	0.57	33	
7/10/20 12:12 PM	0:52:00	5.92	0.113	52.39	0.67	34	
7/10/20 1:02 PM	1:42:00	6.32	0.121	52.23	0.76	34.6	
7/10/20 1:03 PM	1:43:00	6.32	0.121	52.23	0.76	35.5	
7/10/20 1:55 PM	2:35:00	6.7	0.129	51.94	0.86	36	
7/10/20 1:56 PM	2:36:00	6.7	0.129	51.94	0.86	37.1	
7/10/20 2:50 PM	3:30:00	7.07	0.136	51.99	0.96	37.7	
7/10/20 2:51 PM	3:31:00	7.07	0.136	51.99	0.96	38.5	
7/10/20 3:10 PM	3:50:00	7.07	0.136	51.99	0.96	39.3	
7/10/20 5:00 PM	5:40:00	7.07	0.136	51.99	0.96	39.5	Bumped T-Couple & Reposition.
7/10/20 5:30 PM	6:10:00	7.07	0.136	51.99	0.96	39.5	Adjusted values.
7/13/20 8:30 AM	69:10:00	7.07	0.136	51.99	0.96	39.5	
7/13/20 5:05 PM	77:45:00	7.07	0.136	51.99	0.96	39.8	
7/14/20 9:45 AM	94:25:00	7.07	0.136	51.99	0.96	39.8	
7/14/20 5:30 PM	102:10:00	7.07	0.136	51.99	0.96	40.1	
7/15/20 3:30 PM	124:10:00	7.07	0.136	51.99	0.96	40.6	
7/16/20 11:30 AM	144:10:00	7.07	0.136	51.99	0.96	42.3	
7/27/20 12:00 PM	408:40:00	7.07	0.136	51.99	0.96	43.3	Stop Test.

Figure 17. Data log of Burn-in: time, voltage, current, power, resistance*, and DUT top temperature (* = calculated).*

The device underwent a final post-burn-in RF test to further confirm there was no damage to the device due to the Burn-in (Figure 18). Note that the same connectors were used throughout the test and never removed. As Figure 18 shows, there was no observable degradation in the RF performance of the DUT in the post-burn test. Based on the data provided we can conclude that the broadband high frequency attenuator, TSX family can handle 1 Watt of power when properly mounted.

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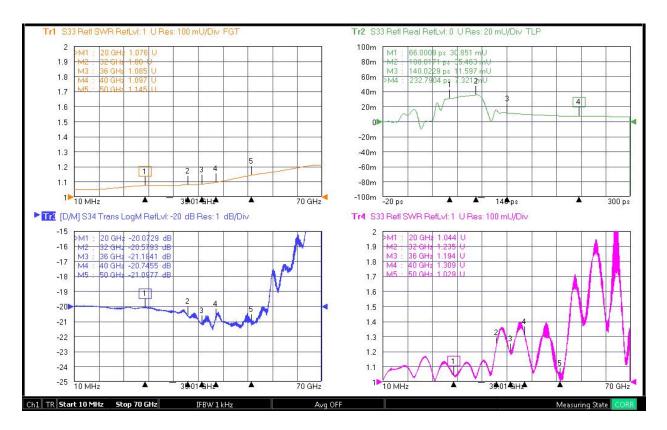


Figure 18. Post-burn-in RF Performance: gated VSWR (Tr1), ungated VSWR (Tr4), Attenuation (Tr3), Time Domain (Tr2)

Qualification Test

The purpose of this test was to subject the broadband high frequency attenuators of TSX series to the conditions as specified in the test plan TP-9293 and qualify them internally for the markets to be served. Five representative samples from the high, mid and low attenuation values selected for the Qualification Test: 3dB, 6dB, & 20dB represented the entire part family. Group A inspection was performed on 100% of the lot. Group B and C inspections were performed in the following quantities - three representative samples of each value for Group B and two representative samples of each value for Group C. Tests not performed in this qualification were considered by similarity to other products of similar materials and construction that have successfully undergone such tests. The Specification Control Drawing (SCD, see Table 1) of the device was the governing document for all specification limits for each test, with any exceptions noted in the test plan TP-9293. Qualification testing references MIL-PRF-55342 for Class L devices with the exceptions noted in the test plan TP-9293. Devices were mounted on destruct fixturing in order to facilitate performance of the required tests. Removable RF connectors were mounted only when RF test was called out. Test frequencies were defined DC to 50 GHz in increments of 10 GHz. Change in resistance incurred by tests performed was noted (if any) and used for the specification risk assessment and the final device rating. All electrical tests were conducted at DC as power handling is the main concern for the qualification. RF performance was verified at the end of each test group. Figure 19 shows the qualification test flow chart.

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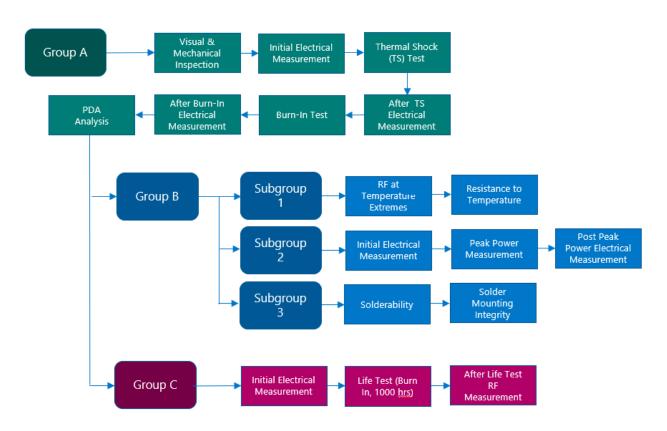


Figure 19. Flowchart of Test Procedure

GROUP A INSPECTION (15 samples; 5 pcs of each 3 dB, 6 dB, 20 dB)

Five representative samples of 3 dB, 6 dB, and 20 dB attenuators were selected and mounted to their appropriate PCB carriers for test. Test Board RF Connectors might have been removed to prevent possible damage incurred by test and replaced for post-test RF measurements.

Visual Mechanical Inspection Results

The materials, design, construction, physical dimensions, markings and workmanship were verified to be in accordance with applicable requirements per the appropriate SCD.

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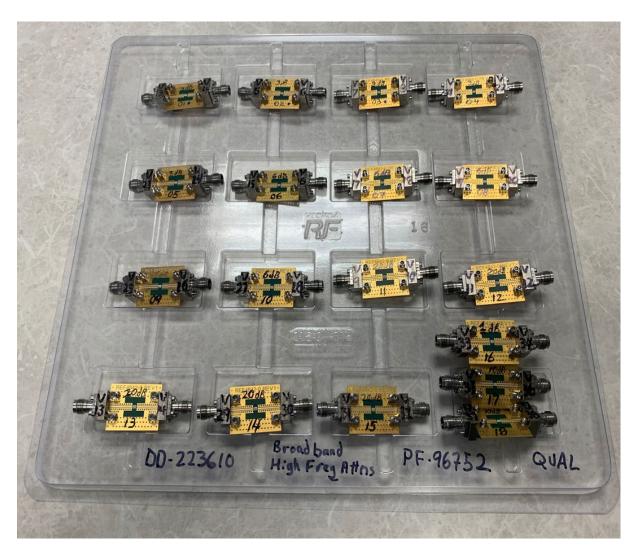


Figure 20. Group A inspection lot: test fixtures with the connectors installed

Initial Electrical (INI) Test Results

VSWR and attenuation at the mid band were measured and recorded according to the frequency band of the part number at $23^{\circ}C \pm 3^{\circ}C$. The S-parameters were recorded at minimum, across the device's frequency band. Acceptance limits for VSWR and attenuation as per SCD (see Table 1) adjusted for the test fixture (test board and test connector) impact. All samples of the Group A passed initial RF test (see Table 2).

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TSX Series,	Qualificat	ion Acc	eptance T	esting, TP	-9293		ths inter	connec	t	
Project / WO:	DD-233610 /		•			bringing t	technology to life	1		1
Part #:	TSX0604XX.									
Description:			and Attenuator							
Test Plan:	TP-9293									
Test Stage:	2.2.1									
Test Descr:	Initial RF (IN	l)								
Test Equip:	Anritsu MS46	647B VNA 1	FE91819					Results	P	ASS
Operator:	JA 11/0/2020									
Start Date: End Date:	11/9/2020 11/13/2020									
Specifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	1		
Part Value	Attn (dB)	VSWR :1	VSWR :1	VSWR :1	Attn Tol. (±) (dB)	Attn Tol.(±) (dB)		1		
TS060403.00F	-3.0	1.20	1.30	1.50	0.50	0.75	1.05			
TS060406.00F	-6.0	1.20	1.30	1.50	0.50	0.80	1.32			
TS060420.00F	-20.0	1.20	1.30	1.50	0.50	0.90	1.80			
TS060402.00F										
TS060403.00F Frequency	VSWR :1	VSWR :1	VSWR :1	VSWR :1	VSWR :1	ATTN dB	ATTN dB	ATTN dB	ATTN dB	ATTN dB
(GHz)	01	02	03	04	05	01	02	03	04	05
0.01	1.02	1.02	1.01	1.01	1.02	-2.50	-2.51	-3.18	-3.05	-3.00
10	1.04	1.04	1.02	1.07	1.05	-2.62	-2.60	-3.06	-3.12	-3.07
20	1.08	1.09	1.09	1.16	1.14	-2.68	-2.60	-3.21	-3.11	-3.12
30	1.14	1.15	1.16	1.21	1.25	-2.63	-2.65	-3.31	-3.16	-3.25
40	1.11	1.13	1.15	1.18	1.27	-2.82	-2.88	-3.50	-3.31	-3.60
50	1.01	1.01	1.05	1.06	1.20	-3.16	-3.23	-3.79	-3.79	-3.94
TS060406.00F										
Frequency	VSWR :1	VSWR :1	VSWR :1	VSWR :1	VSWR :1	ATTN dB	ATTN dB	ATTN dB	ATTN dB	ATTN dB
(GHz)	06	07	08	09	10	06	07	08	09	10
0.01	1.02	1.02	1.02	1.03	1.04	-5.52	-5.70	-5.50	-6.15	-6.12
10	1.01	1.01	1.01	1.04	1.03	-5.62	-5.61	-5.60	-6.11	-6.12
20	1.03	1.03	1.02	1.05	1.06	-5.61	-5.67	-5.60	-6.06	-6.12
30	1.07	1.07	1.08	1.08	1.09	-5.67	-5.86	-5.64	-6.12	-6.23
40	1.07	1.07	1.12	1.08	1.09	-6.07	-6.16	-6.09	-6.45	-6.67
50	1.04	1.03	1.06	1.03	1.05	-6.63	-6.65	-6.56	-7.15	-7.32
TS060420.00F										
Frequency	VSWR :1	VSWR :1	VSWR :1	VSWR :1	VSWR :1	ATTN dB	ATTN dB	ATTN dB	ATTN dB	ATTN dB
(GHz)	11	12	13	14	15	11	12	13	14	15
0.01	1.05	1.03	1.05	1.03	1.04	-19.50	-19.50	-19.50	-20.00	-20.00
10	1.05	1.05	1.06	1.05	1.05	-19.50	-19.60	-19.60	-20.00	-20.00
20	1.07	1.08	1.10	1.09	1.09	-19.60	-19.60	-19.60	-20.00	-20.00
30	1.07	1.09	1.11	1.10	1.11	-19.70	-19.80	-19.70	-20.20	-20.10
40	1.08	1.10	1.15	1.10	1.13	-20.60	-20.60	-20.60	-20.90	-20.80
50	1.09	1.14	1.18	1.10	1.16	-21.40	-21.80	-21.40	-20.90	-21.10
Note: One 1dB a	nd two 10dB d	evices wer	e tested in Gr	oup A, outside	of the Test Plan,	as there were ex	xtra connectors			
Specifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	1		
Part Value	Attn (dB)	VSWR :1		VSWR :1			Attn Tol. (±) (dB)	1		
TS060401.00F	-1.0	1.20	1.40	1.80	0.50	0.75	1.00	1		
TS060410.00F	-10.0	1.20	1.40	1.80	0.50	0.75	1.00			
TS060401.00F	_									
Frequency	VSWR :1	ATTN dB	1							
(GHz)	16	16								
0.01	1.03	-1.46								
10	1.05	-0.84								
20	1.15	-0.96								
30	1.22	-1.06								
40	1.15	-1.55								
50	1.18	-1.97								
TS060410.00F	Volute	VOVE	ATT: 15							
Frequency	VSWR :1	VSWR :1		ATTN dB						
(GHz)	17 1.03	18 1.03	17 -9.73	-9.57						
0.01	1.05			-9.57						
0.01	1 00	1 0 2								
10	1.02	1.02	-9.59							
10 20	1.01	1.01	-9.55	-9.58						
10										

Table 2. Group A Initial Electrical Test Results – Summary

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Below is a plot of the thruline used to normalize the test fixture loss. It can be observed that the response becomes less stable at frequencies above 37GHz.

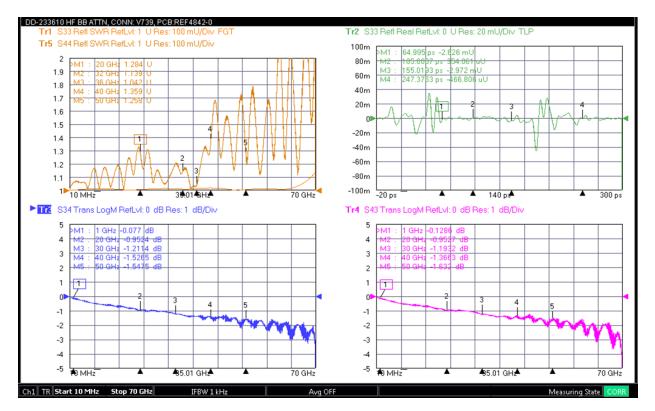


Figure 21. Thruline test fixture RF performance

Thermal Shock

The inspection lot samples were exposed to 10 cycles of thermal shock, -55° C to $+125^{\circ}$ C in accordance with MIL-STD-202, Method 107 (see Table 3). The equipment used for the test consisted of Thermotron, model ATS-30-4-4 with the asset tag # TE90075.

STEP	TEMPERATURE (°C)	TIME (MINUTES)
1	-55 (+0/-3)	15 min.
2	+25 (+10/-5)	5.0 max.
3	+125 (+3/-0)	15 min.
4	+25 (+10/-5)	5.0 max.

Table 3. Thermal Shock temperature levels and exposure times

After Thermal Shock Electrical (ATS) Test Results

VSWR and attenuation at the mid band were measured and recorded according to the frequency band of the part number at $23^{\circ}C \pm 3^{\circ}C$. The s-parameters were recorded at minimum, across the device's frequency band. Acceptance limits for VSWR and attenuation as per SCD (see Table 1) adjusted for the test fixture (test board and test connector) impact. All samples of the Group A passed post-thermal shock RF test (see Table 4).

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ion deries,	Qualification	Acceptance	Testing, TP-9	293			chnology to life	connect		
Drainet / W/O:	DD-233610 / PF-9	2570				bringing te	chinology to the			
Project / WO: Part #:	TSX0604XX.00X	0572								
Description:	High Frequency Br	oadband Attenuato	r							
lest Plan:	TP-9293									
Test Stage:	2.2.3									
Test Descr:	After Thermal Shoo	k (ATS) RF						Results	PA	SS
Test Equip:	Anritsu MS4647B \									
Operator:	JA									
Start Date:	11/12/2020									
End Date:	11/16/2020									
Specifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz			
Part Value	Attn (dB)	VSWR :1	VSWR :1	VSWR :1	Attn Tol. (±) (dB)	Attn Tol.(±) (dB)	Attn Tol. (±) (dB)			
TS060403.00F	-3.0	1.20	1.30	1.50	0.50	0.75	1.05			
TS060406.00F	-6.0	1.20	1.30	1.50	0.50	0.80	1.22			
TS060420.00F	-20.0	1.20	1.30	1.50	0.50	0.90	1.80			
TS060403.00F										
Frequency	VSWR :1	VSWR :1	VSWR :1	VSWR :1	VSWR :1	ATTN dB	ATTN dB	ATTN dB	ATTN dB	ATTN dB
(GHz)	01	02	03	04	05	01	02	03	04	05
0.01	1.01	1.01	1.00	1.04	1.02	-2.54	-2.53	-3.03	-3.02	-3.01
10	1.04	1.04	1.03	1.07	1.05	-2.61	-2.56	-3.07	-3.06	-3.05
20	1.08	1.09	1.10	1.18	1.14	-2.73	-2.68	-3.14	-3.17	-3.19
30	1.13	1.15	1.17	1.24	1.24	-2.74	-2.76	-3.21	-3.27	-3.23
40	1.10	1.12	1.15	1.20	1.27	-2.88	-2.98	-3.45	-3.48	-3.74
50	1.01	1.01	1.04	1.07	1.20	-3.17	-3.38	-3.81	-4.02	-4.04
TS060406.00F				101115						
Frequency	VSWR :1	VSWR :1	VSWR :1	VSWR :1	VSWR :1	ATTN dB	ATTN dB	ATTN dB	ATTN dB	ATTN dB
(GHz)	06	07 1.02	08	09	10	06	07	08	09 -6.24	10
0.01	1.02		1.02	1.03	1.04	-5.55	-5.53	-5.59		-6.06
10 20	1.01	1.01 1.03	1.00 1.02	1.04 1.05	1.03	-5.60 -5.68	-5.60 -5.71	-5.60 -5.67	-6.10 -6.13	-6.09 -6.15
30	1.03	1.06	1.02	1.05	1.09	-5.81	-5.84	-5.79	-6.27	-6.31
40	1.08	1.06	1.12	1.08	1.09	-6.11	-6.14	-6.16	-6.38	-6.49
50	1.08	1.03	1.06	1.08	1.09	-6.72	-6.68	-6.62	-7.15	-0.49
TS060420.00F										
Frequency	VSWR :1	VSWR :1	VSWR :1	VSWR :1	VSWR :1	ATTN dB	ATTN dB	ATTN dB	ATTN dB	ATTN dB
(GHz)	11	12	13	14	15	11	12	13	14	15
0.01	1.05	1.05	1.05	1.03	1.04	-19.50	-19.60	-19.50	-20.00	-20.00
10	1.05	1.05	1.06	1.05	1.05	-19.50	-19.60	-19.60	-20.10	-20.00
20	1.08	1.08	1.10	1.09	1.08	-19.60	-19.70	-19.60	-20.10	-20.00
30	1.07	1.09	1.11	1.10	1.11	-19.90	-20.10	-19.90	-20.20	-20.20
40	1.08	1.10	1.15	1.11	1.13	-20.60	-20.60	-20.60	-20.90	-20.80
50	1.09	1.14	1.18	1.11	1.16	-21.50	-21.80	-21.50	-21.00	-21.10
Note: One 1dB ar	nd two 10dB devices	were tested in G	roup A, outside o	f the Test Plan, as	s there were extra	connectors				
Specifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz			
Part Value	Attn (dB)	VSWR :1	VSWR :1	VSWR :1	Attn Tol. (±) (dB)	Attn Tol.(±) (dB)	Attn Tol. (±) (dB)			
TS060401.00F	-1.0	1.20	1.40	1.80	0.50	0.75	1.04			
TS060410.00F	-10.0	1.20	1.40	1.80	0.50	0.75	1.04			
TS060401.00F										
Frequency	VSWR :1	ATTN dB								
(GHz)	16	16	1							
0.01	1.03	-0.74								
10	1.05	-0.80								
20	1.15	-0.98								
30	1.22	-1.08								
40	1.15	-1.49								
50	1.19	-2.04								
TS060410.00F	_									
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB						
	17	18	17	18						
(GHz)	1.03	1.03	-9.58	-9.61						
0.01				0.00	1					
0.01	1.02	1.02	-9.60	-9.63						
0.01 10 20	1.02	1.01	-9.60	-9.65						
0.01 10 20 30	1.02 1.04	1.01 1.04	-9.60 -9.63	-9.65 -9.69						
0.01 10 20	1.02	1.01	-9.60	-9.65						

Table 4. Group A Post Thermal Shock Electrical Inspection Results

Bake (100% de-rated burn-in):

The devices were subjected to a 100-hour stabilization at 150°C. This test is the equivalent of a 100% de-rated power burn in.The equipment used in the test – Fischer Scientific Isotemp oven with an asset tag # TE91660 and Omega HH502 thermometer with an asset tag TE40080. The entire lot was placed in the appropriate burn in fixture for the product family (Figure 22). The fixture was placed in the appropriate temperature controlled preheated chamber. The power was

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turned on and 168-hour test started. The temperature was monitored periodically to ensure test is not disrupted. After 168 hours had been concluded, the parts were removed from the chamber and stabilized at the room temperature until tray was cool (1 hour min).



Figure 22. Burn-in test Equipment – Fischer Scientific Isotemp oven and Omega HH502 thermometer

After Burn-in Electrical Test Results

VSWR and attenuation at the mid band were measured and recorded according to the frequency band of the part number at $23^{\circ}C \pm 3^{\circ}C$. The s-parameters were recorded at minimum, across the device's frequency band. Acceptance limits for VSWR and attenuation as per SCD (see Table 1) adjusted for the test fixture (test board and test connector) impact. All samples of the Group A passed post-bake RF test (see Table 5).

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TCV Carias	Qualification	Accentors	Testing T	0.000		sm	iths inte	erconr	nect	
ISX Series,	Qualification	Acceptance	e resting, TF	-9293			g technology to life	- Corn		
Project / WO: Part #:	DD-233610 / PF- TSX0604XX.00X									
Description:		Broadband Attenua	ator							
Test Plan:	TP-9293									
Test Stage:	2.2.5									
Test Descr:	After Burn-In (AE							Results	PA	SS
Test Equip:	Anritsu MS4647B	8 VNA TE91819								
Operator:	JA									
Start Date: End Date:	11/23/2020 11/26/2020									
Specifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz			
Part Value	Attn (dB)	VSWR :1	VSWR :1	VSWR :1			Attn Tol. (±) (dB)		
TS060403.00F	-3.0	1.20	1.30	1.50	0.50	0.75	1.05			
TS060406.00F	-6.0	1.20	1.30	1.50	0.50	0.80	1.30			
TS060420.00F	-20.0	1.20	1.30	1.50	0.50	0.90	1.80			
TS060403.00F										
Frequency	VSWR :1	VSWR :1	VSWR :1	VSWR :1	VSWR :1	ATTN dB	ATTN dB	ATTN dB	ATTN dB	ATTN dB
(GHz)	01	02	03	04	05	01	02	03	04	05
0.01	1.02	1.01	1.01	1.03	1.02	-2.70	-2.57	-2.97	-2.96	-2.97
10 20	1.04	1.04 1.09	1.03	1.01 1.07	1.05	-2.63	-2.57 -2.67	-3.05	-3.08	-3.07 -3.18
20	1.08	1.09	1.09 1.17	1.07	1.14	-2.70 -2.73	-2.67	-3.12 -3.20	-3.12 -3.20	-3.18 -3.42
40	1.10	1.14	1.17	1.10	1.24	-2.73	-2.91	-3.38	-3.20	-3.42
50	1.01	1.01	1.16	1.20	1.27	-2.82	-2.94	-3.36	-3.42	-4.01
TS060406.00F Frequency	VSWR :1	VSWR :1	VSWR :1	VSWR :1	VSWR :1	ATTN dB	ATTN dB	ATTN dB	ATTN dB	ATTN dB
(GHz)	06	07	08	09	10	06	07	08	09	10
0.01	1.02	1.02	1.02	1.04	1.04	-5.55	-5.73	-5.53	-6.01	-6.00
10	1.01	1.01	1.01	1.04	1.03	-5.60	-5.62	-5.61	-6.12	-6.09
20	1.03	1.02	1.02	1.05	1.06	-5.69	-5.76	-5.70	-6.15	-6.15
30	1.07	1.06	1.08	1.08	1.09	-5.82	-5.98	-5.81	-6.33	-6.30
40	1.08	1.06	1.12	1.07	1.09	-6.16	-6.36	-6.16	-6.69	-6.62
50	1.04	1.03	1.06	1.02	1.05	-6.76	-6.73	-6.65	-7.21	-7.30
TS060420.00F										
Frequency	VSWR :1	VSWR :1	VSWR :1	VSWR :1	VSWR :1	ATTN dB	ATTN dB	ATTN dB	ATTN dB	ATTN dB
(GHz)	11	12	13	14	15	11	12	13	14	15
0.01	1.04	1.05	1.05	1.04	1.04	-19.50	-19.60	-19.90	-20.00	-20.00
10	1.06	1.05	1.06	1.07	1.05	-19.50	-19.60	-19.50	-20.10	-20.00
20 30	1.10	1.08 1.09	1.10 1.12	1.13 1.16	1.09	-19.50 -19.80	-19.70 -20.00	-19.70 -19.90	-20.00 -20.20	-20.00 -20.20
40	1.12	1.10	1.12	1.18	1.13	-20.60	-20.00	-20.80	-20.20	-20.20
50	1.14	1.10	1.18	1.10	1.16	-21.30	-21.70	-21.50	-20.90	-20.00
Note: One 1dB ar	nd two 10dB devic	es were tested in	Group A. outside	of the Test Pla	n. as there wer	e extra connect	ors			
Specifications: Part Value	Attn (dB)	≤ 20GHz VSWR :1	20GHz - 40GHz VSWR :1	40GHz - 50GHz VSWR :1	≤ 20GHz Attn Tol. (±) (dB	20GHz - 40GHz Attn Tol.(±) (dB	40GHz - 50GHz Attn Tol. (±) (dB)		
TS060401.00F	-1.0	1.20	1.40	1.80	0.50	0.75	1.04			
TS060410.00F	-10.0	1.20	1.40	1.80	0.50	0.75	1.00			
TS060401.00F										
Frequency	VSWR :1	ATTN dB								
(GHz)	16	16								
0.01	1.03	-0.69								
10	1.05	-0.83								
20	1.15	-0.97								-
30 40	1.22	-1.08 -1.45								
40 50	1.15	-1.45 -2.01								
TS060410.00F										
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB						
(GHz)	17	18	17	18						
0.01	1.03	1.03	-9.60	-9.58						
10	1.02	1.02	-9.61	-9.62						
20	1.02	1.01	-9.64	-9.68						
30	1.05	1.04	-9.73	-9.78						
40	1.03	1.07	-10.30	-10.40						
50		1.04	-9.86	-9.97						

Table 5. Group A Post Burn In Electrical Test Results – Summary

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Percent Defective Allowable (PDA) Analysis Results

Percentage Defective Allowable (PDA) Analysis was performed on the Group A inspection lot. The defective percentage was calculated to be 0% which is below an acceptable 5% (see Figure 23). It was concluded that the inspection lot that was subjected to the test passed the Group A testing and could be moved over to the Group B test stage.

smiths interconn		lysis Repor	t	
Shop Order Part Number	DD-233610/PF-96572 TSX0604XX.00X	_ Date _ Done by	11/26/20 JA	
Initial quantity PDA required		-	18 5.00%	= q = PDA
Qty rejected	to testing process by 100% visual QC during initial electrical ses	- - - -	0	= d1
Quantity enter	ed to the testing process	C	18	Q = q - d1
Defects not re Broken piece Missing piec		ss [0	= d2
Defects relate VSWR over Attenuation to Attenuation to Delta over sp Delta below s	over spec below spec bec	- - - - - - - - - - - - - 	0	= d3
Total defective	es after testing process	Γ	0	D = d2 + d3
Final quantity			18	F = Q - D
RESULT	centage in the order	L	0.00% PASS	P = D / Q P < PDA

Figure 23. PDA Analysis - Results

GROUP B INSPECTION (9 samples; 3 pcs of each 3 dB, 6 dB, 20 dB)

Devices from the Group A inspection were divided into Electrical and Mechanical subgroups. Each subgroup (1, 2, 3) consisted of three (3) devices, one (1) from each value. No Group B failures were allowed.

SUBGROUP 1 (3 devices, 1 from each value) TEST RESULTS

VSWR and attenuation were measured and recorded at the low, mid and high frequencies band according to the frequency band of the part number at $-55^{\circ}C + 0^{\circ}-3^{\circ}C$, $23^{\circ}C \pm 3^{\circ}C$, and $\pm 125^{\circ}C \pm 3^{\circ}-0^{\circ}C$. S-Parameters were recorded at minimum, across the device's frequency band. Acceptance limits were established as per SCD (see Table 1). All three samples of the Group B, Subgroup 1 passed RF test at temperature extremes (see Table 6).

Project / WO:	DD-233610 / PF-965	572				
Part #:	TSX0604XX.00X					
Description:	High Frequency Bro	adband Attenuator				
				Results	PA	SS
Test Plan:	TP-9293					
Test Stage:	3.1.1					
Fest Descr:	RF at Temperature E	xtremes				
Test Equip:	Anritsu 37369D VNA	(TE 91590), Thermo	onics T-2500E Temp	o forcing system (TE4	10071), Omega HH502	2 Thermometer (TE
Operator:	JA/ BP					
Start Date:	12/16/2020					
End Date:	12/16/2020					
Specifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz
Part Value	Attn (dB)	VSWR :1	VSWR :1	VSWR :1	Attn Tol. (±) (dB)	Attn Tol.(±) (dB
TS060403.00F	-3.0	1.20	1.30	1.50	0.50	0.75
TS060406.00F	-6.0	1.20	1.30	1.50	0.50	0.75
TS060420.00F	-20.0	1.20	1.30	1.56	0.65	0.75
TS060403.00F						
Frequency	VSWR :1	VSWR :1	VSWR :1	ATTN dB	ATTN dB	ATTN dB
(GHz)	125C	25C	-55C	125C	25C	-55C
0.01	1.02	1.02	1.02	-3.01	-2.98	-2.99
10	1.14	1.14	1.16	-3.13	-3.03	-2.98
20	1.13	1.13	1.23	-3.23	-3.09	-3.00
30	1.14	1.15	1.19	-3.44	-3.23	-3.11
40	1.22	1.20	1.26	-3.73	-3.35	-3.30
TS060406.00F						
Frequency	VSWR :1	VSWR :1	VSWR :1	ATTN dB	ATTN dB	ATTN dB
(GHz)	125C	25C	-55C	125C	25C	-55C
0.01	1.02	1.01	1.02	-6.02	-6.01	-6.02
10	1.16	1.16	1.18	-6.16	-6.09	-6.01
20	1.06	1.09	1.14	-6.20	-6.07	-5.95
30	1.16	1.10	1.15	-6.41	-6.20	-6.05
40	1.09	1.15	1.10	-6.65	-6.46	-6.15
TS060420.00F						
Frequency	VSWR :1	VSWR :1	VSWR :1	ATTN dB	ATTN dB	ATTN dB
(GHz)	125C	25C	-55C	125C	25C	-55C
0.01	1.02	1.01	1.00	-19.42	-19.37	-19.41
10	1.12	1.11	1.08	-19.56	-19.48	-19.36
20	1.15	1.23	1.23	-19.64	-19.55	-19.36
30	1.07	1.09	1.04	-19.91	-19.73	-19.43
40	1.18	1.06	1.15	-20.67	-20.57	-20.05

Table 6. Group B – Subgroup 1 Electrical Test Results – Summary

Group B, Subgroup 1 devices were also tested for their resistance to temperature characteristic in accordance with MIL-STD-202, Method 304. The following details and exceptions applied:

- a. Reference temperature: Room ambient temperature.
- b. Test temperatures:

Step 1: Room temperature. Step 2: -55°C. Step 3: Room temperature. Step 4: +125°C.

c. Accuracy of temperature measurement: Devices shall be maintained within 3°C of each test temperature for a period of 30 to 45 minutes.

Acceptance limits were established as per SCD (see Table 1). All three samples of the Group B, Subgroup 1 passed the resistance to temperature characteristics test (see Table 7).

				ance Testin	g, TP-9293	smiths bringing technology		nnect
Project / WO:			6572					
Part #:	TSX0604XX							
Description:	High Freque	ncy Br	oadband Attenu	ator				
Test Plan:	TP-9293							
Test Stage:	3.1.2							
Test Descr:	Resistance T	emper	ature Character	istics				
Test Equip:					DE Temp forcing	system (TE40071)). Omega HH502	2 Thermometer (
Operator:	JA/AM						<u> </u>	`
Start Date:	1/7/2021							
End Date:	1/11/2021							
Specifications						Results	PA	SS
opeenieutiene	Attn		Rab (Ω)	Rac / Rbc (Ω)				
Attn (dB):	3	dB	17.5	152.00				
	6	dB	33	85				
	20	dB	81.82	51.01				
Tol. (±):	0.5	dB						
Tol. (±):	0.75	dB						
DCR Tol. (±):	5.0	%						
Zin / Zout:	50	Ω						
PPM (±):	200	/°C						
Ref #	Attn value		Rab (Ω)	Rac (Ω)	Rbc (Ω)	Rab (ppm/C)	Rac (ppm/C)	Rbc (ppm/C)
SN04 25C	3dB		17.28	152.38	152.34	Δ25C to -55C	Δ25C to -55C	Δ25C to -55C
SN04 -55C	3dB		17.43	153.38	153.85	105.60	82.36	123.90
SN04 125C	3dB		17.23	151.09	150.65		Δ25C to 125C	
SN04_25C	3dB		17.28	152.38	152.35	31.35	85.51	112.91
0100.050	0.15		00.04	00.50	00.74			A070 (
SN09_25C	6dB		33.64	83.56	83.74		Δ25C to -55C	
SN0955C	6dB		33.97	84.08	84.55	124.11	77.34	120.46
SN09_125C	6dB		33.21	83.04	83.04		Δ25C to 125C	
SN09_25C	6dB		33.47	83.52	83.56	77.68	57.20	62.62
SN11_25C	20dB		79.66	50.53	50.58	Δ25C to -55C	Δ25C to -55C	Δ25C to -55C
SN1155C	20dB		80.30	50.95	51.01	101.69	103.15	105.27
SN11_125C	20dB		78.95	50.09	50.13	Δ25C to 125C	Δ25C to 125C	Δ25C to 125C
SN11 25C	20dB		79.66	50.53	50.59	89.55	88.04	91.16

Table 7. Group B – Subgroup 1 Resistance to Temperature Test Results – Summary

SUBGROUP 2 (3 devices, 1 from each value) TEST RESULTS

Subgroup 2 consisted of three (3) devices, one (1) of each value which have completed Group A. The samples were subjected to a 10 μ s pulse at a 10% duty cycle (1 millisecond period), pulsed DC Voltage of an amplitude equivalent to ten times the maximum power as specified in the SCD (10W). The samples were properly terminated and mounted to a suitable heatsink (see Figure 24) for a duration of 1.0 ± 0.1 hour in each direction per MIL-DTL-3933, Method 4.7.11.7. The units were allowed to stabilize at $25^{\circ}C \pm 5^{\circ}C$ for 1-hour minimum before conducting electrical measurements. Acceptance limits were established as per SCD (see Table 1). All three samples of the Group B, Subgroup 2 passed the peak power test (see Table 8).

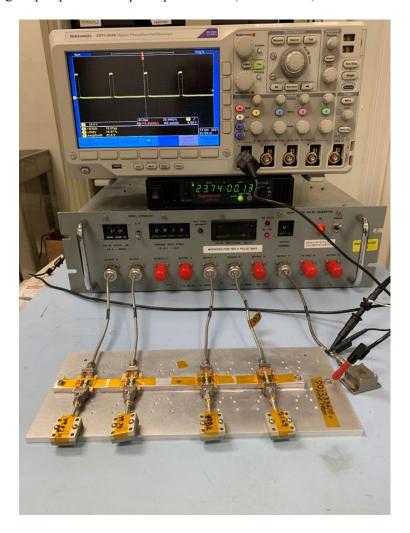


Figure 24. Test setup for the peak power test

bringing technology to life

					E M	iths intera	connect
TSX Series,	Qualification /	Acceptance Te	sting, TP-929	3		technology to life	Unnect
Project / WO:	DD-233610 / PF-96	6572					
Part #:	TSX0604XX.00X						
Description:	High Frequency Br	oadband Attenuator					
	TD 0000				Results	PA	SS
Test Plan:	TP-9293						
Test Stage: Test Descr:	3.2.2 Peak Power	eak Power (12.5W) R					
Test Equip:				ulse Generator So	rensen XG33-25 DC F	Power Supply	
Operator:	JA	(120000), ENO 070					
Start Date:	1/13/2021						
End Date:	1/14/2021						
Specifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz
Part Value	Attn (dB)	VSWR :1	VSWR :1	VSWR :1	Attn Tol. (±) (dB)	Attn Tol.(±) (dB)	Attn Tol. (±) (dB)
TS060403.00F	-3.0	1.20	1.30	1.50	0.50	0.75	1.05
TS060406.00F TS060420.00F	-6.0 -20.0	1.20 1.20	1.30 1.30	1.50 1.50	0.50	0.80	1.30 1.80
13060420.00F	-20.0	1.20	1.30	1.50	0.50	0.90	1.00
TS060403.00F	BPP	BPP			APP	APP	
Frequency	VSWR :1	ATTN dB		∆ ATTN dB	VSWR :1	ATTN dB	
(GHz)	05	05		05	05	05	
0.01	1.02	-3.01		0.03	1.02	-2.98	
10	1.05	-3.06		-0.01	1.05	-3.07	
20	1.14	-3.04		-0.05	1.14	-3.09	
30	1.24	-3.17		0.02	1.24	-3.15	
40 50	1.27	-3.50		-0.05	1.27 1.20	-3.55	
50	1.20	-3.96		-0.01	1.20	-3.97	
TS060406.00F	BPP	BPP		Δ APP	APP	APP	
Frequency	VSWR :1	ATTN dB		∆ ATTN dB	VSWR :1	ATTN dB	
(GHz)	10	10		10	10	10	
0.01	1.04	-6.01		-0.01	1.04	-6.02	
10	1.03	-6.10		0.00	1.03	-6.10	
20	1.05	-6.09		0.01	1.06	-6.08 -6.19	
40	1.09	-6.24 -6.66		0.05	1.09 1.09	-6.52	
50	1.05	-7.25		0.06	1.05	-7.19	
		1.20		0,000			
TS060420.00F	BPP	BPP		Δ APP	APP	APP	
Frequency	VSWR :1	ATTN dB		∆ ATTN dB	VSWR :1	ATTN dB	
(GHz)	12	12		12	12	12	
0.01	1.05	-19.50 -19.60		0.00	1.05 1.05	-19.50 -19.50	
20	1.05	-19.60		-0.04	1.05	-19.50 -19.54	
30	1.09	-19.70		0.10	1.09	-19.60	
40	1.10	-20.60		0.20	1.10	-20.40	
50	1.14	-21.70		0.00	1.14	-21.70	
Note: One 1dB wa	as tested, outside of	r the Test Plan, to te	st the peak power I	andling ability of t	he smallest series re	esistor in the family.	
Specifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz
Part Value	Attn (dB)	VSWR :1	VSWR :1	VSWR :1	Attn Tol. (±) (dB)	Attn Tol.(±) (dB)	Attn Tol. (±) (dB)
TS060401.00F	-1.0	1.20	1.40	1.80	0.50	0.75	1.04
TS060401.00F	BPP	BPP		Δ ΑΡΡ	APP	APP	
Frequency	VSWR :1	ATTN dB		∆ ATTN dB	VSWR :1	ATTN dB	
(GHz)	16	16		16	16	16	
0.01	1.03	-0.74		0.02	1.03	-0.71	
10	1.05	-0.81		-0.01	1.05	-0.82	
20	1.15	-0.94		0.06	1.15	-0.88	
30	1.22	-1.02		0.10	1.22	-0.92	
40	1.15	-1.38		0.04	1.15	-1.34 -1.99	
50	1.19	-1.99		0.00	1.19		

Table 8. Group B – Subgroup 2 Peak Power Test Results – Summary

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SUBGROUP 3 (3 devices, 1 from each value) TEST RESULTS

Solder Mounting Integrity (Die Shear) Test Results:

Devices were soldered to a suitable substrate. A 2-kilogram force was applied to the chip edge for 30 seconds per MIL-PRF-55342, Method 4.8.13. The devices were then visually inspected for any evidence of mechanical damage. As indicated in Table 9, the subgroup 3 devices passed the test.

TSX Serie	es, Qua	lificatio	n Acce	ptan	ce Testi	ng, TP-92	293			
	·				smiths interconnect					
Project / WO	DD-23361	0 / PF-965	72							
Part #:	TSX0604X	X.00X								
Description:	High Frequ	lency Broa	dband Atte	nuator						
-										
Test Plan:	TP-9293									
Test Stage:	3.3.2									
Test Descr:	Solder Mor	unting Integ	rity (Die S	hear)						
Test Equip:		orce Teste								
Operator:	TFM									
Start Date:	1/13/2021									
End Date:	1/13/2021									
Results:	Pass									
3 dB	2kg for									
SN	30 secs									
03	PASS									
6 dB	2kg for									
SN	30 secs									
06	PASS									
20dB	2kg for									
SN	30 secs									
13	PASS									

Table 9. Group B, Subgroup 2 Solder Mounting Integrity Test Results - Summary

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<u>GROUP C INSPECTION (6 samples, 2 samples per value from Group A):</u>

The Group C inspection lot consisted of six (6) devices, two (2) from each value, that have successfully completed the Group A Inspection test and were then subjected to the Life test as described in the TP-9293. No failures were permitted.

Life Test (1000 hr. Burn-In):

The properly terminated devices were subjected to a DC voltage equivalent to the max power in the SCD (1W) with a base temperature not to exceed $100^{\circ}C \pm 5^{\circ}C$ for a duration of 1000 ± 4 hours. The units were allowed to stabilize at $25^{\circ}C \pm 5^{\circ}C$ for 1-hour minimum before conducting electrical measurements. RF Test measurements were made after 250, 500, and 1000 hours (\pm 8 hours). The test setup is shown in Figure 25.

The devices were visually examined for any evidence of mechanical damage which was not observed. VSWR and attenuation at the mid band were measured and recorded according to the frequency band of the part number at $23^{\circ}C \pm 3^{\circ}C$. The s-parameters were recorded at minimum, across the device's frequency band. Acceptance limits for VSWR and attenuation as per SCD (see Table 1) adjusted for the test fixture (test board and test connector) impact. All six samples of the Group C passed the post life test (see Tables 10–12).



Figure 25. Test setup for the Group C life test

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TSX Series, (Qualification A	Acceptance Te	sting, TP-929	3			smiths bringing technolo	Intercor gy to life	nnect
Project / WO:	DD-233610 / PF-96	572							
Part #:	TSX0604XX.00X								
Description:	High Frequency Bro	adband Attenuator							
est Plan:	TP-9293								
est Stage:	4.2.2								
est Descr:	Life Test 250Hrs (1)	M)							
est Equip:	Anritsu MS4647B V								
	JA	NA 1291019							
perator:									
tart Date:	12/4/2020								
nd Date:	12/4/2020								
pecifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz			
art Value	Attn (dB)	VSWR :1	VSWR :1	VSWR :1	Attn Tol. (±) (dB)	Attn Tol.(±) (dB)			
S060403.00F	-3.0	1.20	1.90	1.50	0.50	0.75			
S060406.00F	-6.0	1.20	1.50	1.50	0.50	0.80			
S060420.00F	-20.0	1.20	1.30	1.50	0.50	1.10			
TS060403.00F						0 - 250 Hrs	1 - 250 Hrs		
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB	_	∆ ATTN dB	∆ ATTN dB	∆ ATTN dB	
(GHz)	01	02	01	02		01	02	01	02
0.01	1.01	1.01	-2.51	-2.51		-0.01	-0.01	-0.01	-0.01
10	1.05	1.03	-2.66	-2.64		0.01	-0.03	0.01	-0.03
20	1.10	1.05	-2.80	-2.89		0.23	0.25	0.23	0.25
30	1.21	1.23	-2.67	-2.78		-0.18	-0.06	-0.18	-0.06
40	1.62	1.83	-2.56	-2.59		-0.25	-0.35	-0.25	-0.35
TS060406.00F						0 - 250 Hrs	1 - 250 Hrs		
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB	1	Δ ATTN dB	Δ ATTN dB	∆ ATTN dB	∆ ATTN d
(GHz)	07	08	07	08		07	08	07	08
0.01	1.01	1.01	-5.50	-5.51		-0.02	-0.03	-0.02	-0.03
10	1.03	1.02	-5.68	-5.58		0.11	-0.06	0.11	-0.06
20	1.03	1.02	-5.99	-5.81		0.35	0.13	0.35	0.13
30	1.11	1.10	-6.08	-5.81		0.26	-0.04	0.26	-0.04
40	1.41	1.32				0.20	-0.26		
40	1.41	1.32	-6.20	-5.93		0.07	-0.20	0.07	-0.26
TS060420.00F						0 - 250 Hrs	1 - 250 Hrs		
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB		∆ ATTN dB	∆ ATTN dB	∆ ATTN dB	∆ ATTN d
(GHz)	14	15	14	15		14	15	14	15
0.01	1.03	1.04	-20.00	-20.00		0.00	0.00	0.00	0.00
10	1.08	1.07	-20.00	-20.00		-0.10	0.00	-0.10	0.00
20	1.12	1.07	-20.10	-20.00		0.10	0.10	0.10	0.10
30	1.12	1.12	-20.30	-20.20	1	0.00	0.00	0.00	0.00
40	1.10	1.12	-20.60	-20.40		-0.50	-0.70	-0.50	-0.70
40	1.27	1.20	-20.00	-20.40		-0.00	-0.11	-0.50	-0.70
ote: One 1dB an	d two 10dB devices	were tested in Grou	p A, outside of the	Test Plan, as there	e were extra connec	tors			
pecifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz			
art Value	Attn (dB)	VSWR :1	VSWR :1	VSWR :1	Attn Tol. (±) (dB)	Attn Tol.(±) (dB)			
S060410.00F	-10.0	1.20	1.40	1.80	0.50	0.75			
TS060410.00F						0 - 250 Hrs	1 - 250 Hrs		
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB		∆ ATTN dB	∆ ATTN dB	∆ ATTN dB	
(GHz)	17	18	17	18		17	18	17	18
0.01	1.02	1.02	-9.55	-9.58		-0.03	-0.02	-0.03	-0.02
10	1.01	1.02	-9.55	-9.65		-0.06	-0.04	-0.06	-0.04
20	1.03	1.02	-9.66	-9.85		0.07	0.22	0.07	0.22
30	1.06	1.06	-9.58	-9.75	1	0.02	0.00	0.02	0.00
40	1.10	1.16	-9.96	-10.20		-0.34	-0.30	-0.34	-0.30

Table 10. Post 250 hours of Life Test Electrical Results - Summary

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TSX Series, C	Qualification A	Acceptance Te	sting, TP-929	3			smiths bringing technolo	untercor gy to life	nnect
Project / WO:	DD-233610 / PF-96	572							
Part #:	TSX0604XX.00X								
Description:	High Frequency Bro	badband Attenuator							
Test Plan:	TP-9293								
Test Stage:	4.2.2								
Test Descr:	Life Test 500Hrs (1)	A/)							
Test Equip:	Anritsu MS4647B V	NA 1E91819							
Operator:	JA								
Start Date: End Date:	12/16/2020 12/17/2020								
Specifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz			
Part Value	Attn (dB)	VSWR :1	VSWR :1	VSWR :1	Attn Tol. (±) (dB)	Attn Tol.(±) (dB)			
TS060403.00F	-3.0	1.20	1.30	1.50	0.50	0.75			
TS060406.00F	-6.0	1.20	1.30	1.50	0.50	0.80			
TS060420.00F	-20.0	1.20	1.30	1.50	0.50	1.10			
TS060403.00F						250 - 500 Hrs	250 - 500 Hrs	0 - 500 Hrs	0 - 500 Hrs
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB		∆ ATTN dB	∆ ATTN dB	∆ ATTN dB	
(GHz)	01	02	01	02	1	01	02	01	02
0.01	1.01	1.01	-2.52	-2.50		0.01	-0.01	0.00	-0.02
10	1.05	1.02	-2.70	-2.84		0.04	0.20	0.05	0.17
20	1.11	1.06	-2.88	-2.93		0.08	0.04	0.31	0.29
30	1.24	1.19	-2.88	-2.84		0.00	0.04	0.03	0.23
40	1.36	1.19	-3.20	-3.04		0.21	0.45	0.39	0.00
TS060406.00F						250 - 500 Hrs	250 - 500 Hrs	0 - 500 Hrs	0 500 11-
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB		Δ ATTN dB	Δ ATTN dB	∆ ATTN dB	
(GHz)	07	08	07	08		07	08	07	08
0.01	1.01	1.01	-5.54	-5.51		0.04	0.00	0.02	-0.03
10	1.02	1.02	-5.68	-5.65		0.00	0.07	0.11	0.01
20	1.03	1.02	-6.02	-5.84		0.03	0.03	0.38	0.16
30	1.04	1.10	-6.16	-5.84		0.08	0.03	0.34	-0.01
40	1.05	1.13	-6.44	-5.95		0.24	0.02	0.31	-0.24
TS060420.00F						250 - 500 Hrs	250 - 500 Hrs	0 - 500 Hrs	0 - 500 Hrs
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB		∆ ATTN dB	∆ ATTN dB	∆ ATTN dB	∆ ATTN dB
(GHz)	14	15	14	15		14	15	14	15
0.01	1.04	1.04	-20.00	-20.00		0.00	0.00	0.00	0.00
10	1.07	1.06	-20.00	-20.00		0.00	0.00	-0.10	0.00
20	1.10	1.07	-20.20	-20.10		0.10	0.10	0.20	0.20
30	1.12	1.10	-20.40	-20.40		0.10	0.20	0.10	0.20
40	1.12	1.07	-21.00	-20.70		0.40	0.30	-0.10	-0.40
Note: One 1dB an	id two 10dB devices	were tested in Grou	p A, outside of the	Test Plan, as there	e were extra connec	tors	0.12		
Specifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz			
Part Value	Attn (dB)	S 20GHZ	VSWR :1	40GHz - 50GHz VSWR :1	Attn Tol. (±) (dB)	Attn Tol.(±) (dB)			
TS060410.00F	-10.0	1.20	1.40	1.80	0.50	0.75			
TS060410.00F						250 - 500 Hrs	250 - 500 Hrs	0 - 500 Hrs	
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB		∆ ATTN dB	∆ ATTN dB	∆ ATTN dB	△ ATTN dE
(GHz)	17	18	17	18		17	18	17	18
0.01	1.02	1.02	-9.56	-9.59		0.01	0.01	-0.02	-0.01
10	1.00	1.01	-9.65	-9.70		0.10	0.05	0.04	0.01
10					1				
	1.01	1.03	-9.73	-9.93		0.07	0.08	0.14	0.30
20	1.01	1.03 1.05	-9.73 -9.63	-9.93 -9.88		0.07	0.08	0.14	0.30

Table 11. Post 500 hours of Life Test Electrical Results - Summary

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TSX Series,	Qualification A	cceptance Te	sting, TP-929	3			smiths i		nect
		· · ·					bringing technology	tolife	
Project / WO:	DD-233610 / PF-96	572							
Part #:	TSX0604XX.00X								
Description:	High Frequency Bro	adband Attenuator							
Test Plan:	TP-9293								
Test Stage:	4.2.2								
Test Descr:	Life Test 1000Hrs (1	W)							
Test Equip:	Anritsu MS4647B VI								
Operator:	JA	CTE01010							
Start Date:	12/4/2020								
End Date:	1/8/2020								
	11012020								
Specifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz			
Part Value	Attn (dB)	VSWR :1	VSWR :1	VSWR :1	Attn Tol. (±) (dB)	Attn Tol.(±) (dB)			
TS060403.00F	-3.0	1.20	1.30	1.50	0.50	0.75			
TS060406.00F	-6.0	1.20	1.30	1.50	0.50	0.80			
TS060420.00F	-20.0	1.20	1.30	1.50	0.50	1.10			
	20.0	1.20	1.00	1.00	0.00	1.10			
TS060403.00F									
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB	1	∆ ATTN dB	∆ ATTN dB	∆ ATTN dB	∆ ATTN dB
(GHz)	01	02	01	02		01	02	01	02
0.01	1.01	1.01	-2.51	-2.52		-0.01	0.02	-0.01	0.00
10	1.05	1.01	-2.65	-2.63		-0.05	-0.21	0.00	-0.04
20	1.10	1.05	-2.81	-2.87		-0.07	-0.21	0.24	0.23
30	1.10	1.19	-2.70	-2.80		-0.18	-0.04	-0.15	-0.04
40	1.21	1.19	-2.62	-2.57		-0.18	-0.47	-0.13	-0.04
40	1.20	1.50	-2.02	-2.31	_	-0.56	-0.47	-0.19	-0.37
TS060406.00F									
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB		∆ ATTN dB	∆ ATTN dB	A ATTN dB	∆ ATTN dB
(GHz)	07	08	07	08		07	08	07	08
0.01	1.02	1.01	-5.52	-5.52		-0.02	0.01	0.00	-0.02
10	1.02	1.02	-5.65	-5.62		-0.03	-0.03	0.08	-0.02
20	1.02	1.02	-5.94	-5.83		-0.08	-0.03	0.30	0.15
30	1.03	1.02	-6.05	-5.84		-0.08	0.00	0.30	-0.01
40	1.04	1.16	-6.32	-5.97		-0.12	0.00	0.19	-0.01
40	1.01	1.10	-0.52	-0.87	J	-0.12	0.02	0.15	-0.22
TS060420.00F									
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB		∆ ATTN dB	∆ ATTN dB		∆ ATTN dB
(GHz)	14	15	14	15		14	15	14	15
0.01	1.04	1.04	-20.00	-20.00		0.00	0.00	0.00	0.00
10	1.07	1.05	-20.00	-20.00		0.00	0.00	-0.10	0.00
20	1.10	1.08	-20.10	-20.00		-0.10	-0.10	0.10	0.10
30	1.12	1.10	-20.30	-20.20		-0.10	-0.20	0.00	0.00
40	1.09	1.11	-21.00	-20.50		0.00	-0.20	-0.10	-0.60
Note: One 1dB ar	nd two 10dB devices	were tested in Grou	p A. outside of the	Test Plan. as there	e were extra connec	tors			
Specifications:		≤ 20GHz	20GHz - 40GHz	40GHz - 50GHz	≤ 20GHz	20GHz - 40GHz			
Part Value	Attn (dB)	VSWR :1	VSWR :1	VSWR :1	Attn Tol. (±) (dB)	Attn Tol.(±) (dB)			
TS060410.00F	-10.0	1.20	1.40	1.80	0.50	0.75			
TS060410.00F									
Frequency	VSWR :1	VSWR :1	ATTN dB	ATTN dB	1	∆ ATTN dB	∆ ATTN dB		∆ ATTN dB
(GHz)	17	18	17	18	1	17	18	17	18
0.01	1.02	1.02	-9.54	-9.61	1	-0.02	0.02	-0.04	0.01
10	1.02	1.01	-9.60	-9.68		-0.02	-0.02	-0.01	-0.01
20	1.02	1.01	-9.60	-9.88		0.05	-0.02	0.15	0.25
30	1.11	1.05	-9.67	-9.00		0.01	-0.03	0.15	0.25
30 40	1.05	1.06	-9.66	-9.75		-0.44	-0.13	-0.64	-0.30
					1	-0.44	-0.00		-0.30

Table 12. Post 1000 hours of Life Test Electrical Results - Summary

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Qualification Test – Summary and Conclusion

The high frequency broadband attenuator family, TSX series, consists of thirteen values ranging from 0 dB to 20 dB. Samples of all values have been tested; the test results presented in this test report are evidence of the performance that meets the required specifications.

A rigorous qualification testing as per TP-9293 has also been performed on a 15-piece inspection lot of the three designs (3 dB, 6 dB, 20 dB). The three designs are chosen as "extremes" covering the entire range of attenuation values. The test consisted of Group A, Group B, and Group C testing; the devices were subjected to thermal shock, burn in test, RF test at temperature extremes, solder mount integrity test, and life test. The results of these qualification tests have been presented in this report. As shown, the inspection lot passed all the specifications as required by the TP-9293 and corresponding SCD. It has therefore been determined that **the products under the qualification tests of the product family TSXDB.00 are qualified to be released into a full production**.

Other designs in this product family whose samples have not been subjected to the qualification test have been characterized by the identical bill of materials and processing router as the previously qualified products. In other words, these designs share the identical constitutive material list and identical set of processing steps used to make them. The only difference is in geometrical shapes of the metalized and resistive features on the front surface of the ceramic substrate. By similarity with the qualified designs, it is determined that these designs **can also be qualified to be released into a full production**.